



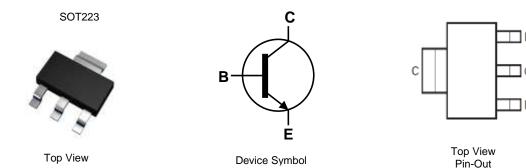
#### 300V NPN MEDIUM POWER TRANSISTOR IN SOT223

### **Features**

- BV<sub>CEO</sub> > 300V
- I<sub>C</sub> = 3.5A High Continuous Collector Current
- I<sub>CM</sub> = 5A Peak Pulse Current
- Very Low Saturation Voltage V<sub>CE(SAT)</sub> < 155mV @ 1A</li>
- R<sub>CE(SAT)</sub> = 87mΩ for a Low Equivalent On-Resistance
- h<sub>FE</sub> Specified Up to 3A for a High Gain Hold-Up
- Complementary PNP Type: FZT957
- Lead-Free Finish; RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

### **Mechanical Data**

- Case: SOT223
- Case Material: Molded Plastic. "Green" Molding Compound.
  UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208
- Weight: 0.112 grams (Approximate)



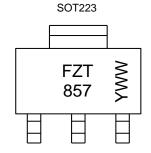
### Ordering Information (Notes 4 & 5)

Product	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
FZT857TA	AEC-Q101	FZT857	7	12	1,000
FZT857QTA	Automotive	FZT857	7	12	1,000

Notes:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to https://www.diodes.com/quality/.
- 5. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

### **Marking Information**



FZT 857 = Product Type Marking Code YWW = Date Code Marking Y or  $\overline{Y}$  = Last Digit of Year (ex: 7 = 2017) WW or  $\overline{W}W$  = Week Code (01–53)



### Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	350	V
Collector-Emitter Voltage	V <sub>CEO</sub>	300	V
Emitter-Base Voltage	V <sub>EBO</sub>	7	V
Continuous Collector Current	I <sub>C</sub>	3.5	Α
Peak Pulse Current	I <sub>CM</sub>	5	Α

## Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Power Dissipation	(Note 6)		3.0 24	W	
Linear Derating Factor	(Note 7)	P <sub>D</sub>	1.6 12.8	mW/°C	
Thermal Desistance Junction to Ambient	(Note 6)	R <sub>0JA</sub>	42		
Thermal Resistance, Junction to Ambient	(Note 7)	R <sub>0JA</sub>	78	°C/W	
Thermal Resistance Junction to Lead (Note 8)		R <sub>0JL</sub>	8.8		
Operating and Storage Temperature Range		T <sub>J.</sub> T <sub>STG</sub>	-55 to +150	°C	

## ESD Ratings (Note 9)

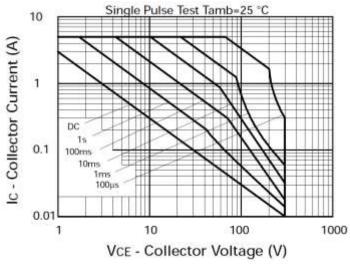
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	8,000	V	3B
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

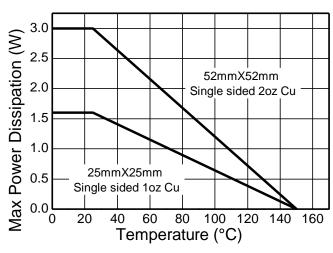
Notes:

- 6. For a device mounted with the collector lead on 52mm x 52mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in steady-state.
- 7. Same as Note 6, except the device is mounted on 25mm x 25mm 1oz copper.
- 8. Thermal resistance from junction to solder-point (at the end of the collector lead).
- 9. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



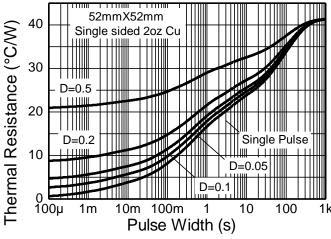
### **Thermal Characteristics and Derating Information**

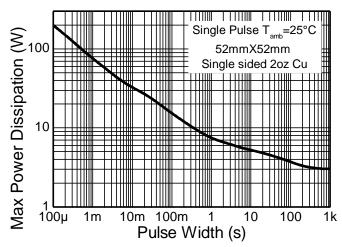




Safe Operating Area







**Transient Thermal Impedance** 

**Pulse Power Dissipation** 



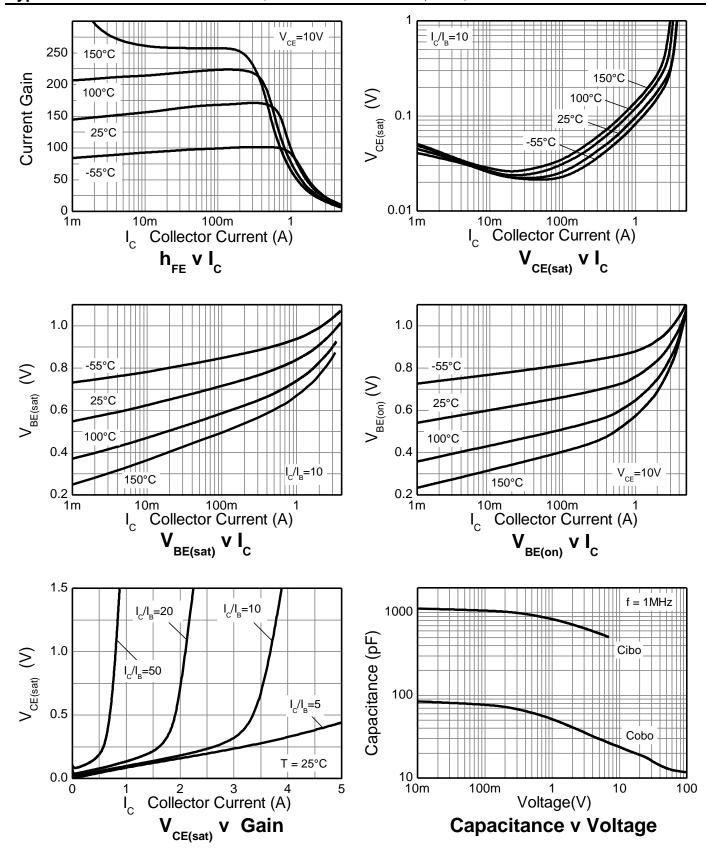
## Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	$BV_CBO$	350	475	_	V	$I_{C} = 100 \mu A$
Collector-Emitter Breakdown Voltage	BV <sub>CER</sub>	350	475	_	V	$I_C = 1\mu A, R_B \le 1k\Omega$
Collector-Emitter Breakdown Voltage (Note 10)	$BV_{CEO}$	300	350	_	V	$I_C = 1mA$
Emitter-Base Breakdown Voltage	$BV_EBO$	7	8	_	V	$I_E = 100\mu A$
Collector Cut-Off Current	I <sub>CBO</sub>	_	<1 —	50 1	nΑ μΑ	V <sub>CB</sub> = 300V V <sub>CB</sub> = 300V, T <sub>A</sub> = +100°C
Collector Cut-Off Current	I <sub>CER</sub>	_	<1 —	50 1	nΑ μΑ	$V_{CE} = 300V, R_B \le 1k\Omega$ $V_{CE} = 300V, T_A = +100^{\circ}C$
Emitter Cut-Off Current	I <sub>EBO</sub>	_	<1	10	nA	$V_{EB} = 6V$
		100	200	_	ı	$I_C = 10 \text{mA}, V_{CE} = 5 \text{V}$
DC Current Gain (Note 10)	h <sub>FE</sub>	100	200	300		$I_C = 500 \text{mA}, V_{CE} = 10 \text{V}$
DC Current Gain (Note 10)		15	25	_		$I_C = 2A$ , $V_{CE} = 10V$
		_	15	_		$I_C = 3A$ , $V_{CE} = 10V$
	V <sub>CE(SAT)</sub>	_	59	100		$I_C = 500 \text{mA}, I_B = 50 \text{mA}$
Collector-Emitter Saturation Voltage (Note 10)		_	95	155	mV	$I_C = 1A$ , $I_B = 100mA$
Collector-Emilier Saturation Voltage (Note 10)		_	180	230	IIIV	$I_C = 2A$ , $I_B = 200mA$
		_	300	345		$I_C = 3.5A$ , $I_B = 600mA$
Base-Emitter Saturation Voltage (Note 10)	$V_{BE(SAT)}$	_	1,020	1,250	mV	$I_C = 3.5A$ , $I_B = 600mA$
Base-Emitter Turn-On Voltage (Note 10)	V <sub>BE(ON)</sub>	_	940	1,120	mV	$I_C = 3.5A, V_{CE} = 10V$
Current Gain-Bandwidth Product (Note 10)	f⊤	_	80	_	MHz	$I_{C} = 100 \text{mA}, V_{CE} = 10 \text{V},$ f = 50 MHz
Output Capacitance	$C_OBO$	_	21	_	pF	$V_{CB} = 20V$ , $f = 1MHz$
Switching Times	t <sub>ON</sub>	_	100	_	ns	$I_C = 250 \text{mA}, V_{CC} = 50 \text{V},$
Owitering Titles	toff	_	5,300	_	110	$I_{B1} = -I_{B2} = 25mA$

Note: 10. Measured under pulsed conditions. Pulse width  $\leq$  300 $\mu$ s. Duty cycle  $\leq$  2%.



# Typical Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

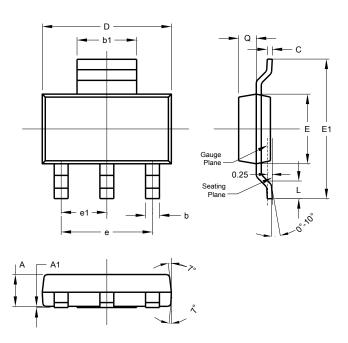




## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### **SOT223**

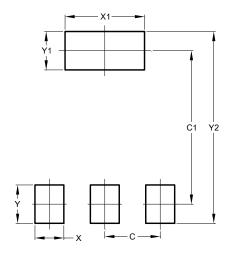


SOT223					
Dim	Min	Max	Тур		
Α	1.55	1.65	1.60		
A1	0.010	0.15	0.05		
b	0.60	0.80	0.70		
b1	2.90	3.10	3.00		
С	0.20	0.30	0.25		
D	6.45	6.55	6.50		
Е	3.45	3.55	3.50		
E1	6.90	7.10	7.00		
е	-	-	4.60		
e1	-	-	2.30		
L	0.85	1.05	0.95		
Q	0.84	0.94	0.89		
All Dimensions in mm					

## **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### **SOT223**



Dimensions	Value (in mm)
С	2.30
C1	6.40
Х	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00

Note: For high voltage applications, the appropriate industry sector guidelines should be considered with regards to creepage and clearance distances between device terminals and PCB tracking.

March 2017

© Diodes Incorporated



#### **IMPORTANT NOTICE**

DIODES INCORPORATED MAKES NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. Diodes Incorporated does not assume any liability arising out of the application or use of this document or any product described herein; neither does Diodes Incorporated convey any license under its patent or trademark rights, nor the rights of others. Any Customer or user of this document or products described herein in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on Diodes Incorporated website, harmless against all damages.

Diodes Incorporated does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel. Should Customers purchase or use Diodes Incorporated products for any unintended or unauthorized application, Customers shall indemnify and hold Diodes Incorporated and its representatives harmless against all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application.

Products described herein may be covered by one or more United States, international or foreign patents pending. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks.

This document is written in English but may be translated into multiple languages for reference. Only the English version of this document is the final and determinative format released by Diodes Incorporated.

#### **LIFE SUPPORT**

Diodes Incorporated products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Diodes Incorporated. As used herein:

- A. Life support devices or systems are devices or systems which:
  - 1. are intended to implant into the body, or
  - 2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.
- B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

Copyright © 2017, Diodes Incorporated

www.diodes.com

# **X-ON Electronics**

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Bipolar Transistors - BJT category:

Click to view products by Diodes Incorporated manufacturer:

Other Similar products are found below:

BC559C MCH4017-TL-H MMBT-2369-TR BC546/116 NJVMJD148T4G NTE16 NTE195A IMX9T110 2N4401-A 2N6728 2SA1419T-TD-H 2SB1204S-TL-E 2SC5488A-TL-H FMC5AT148 2N2369ADCSM 2N2907A 2N3904-NS 2N5769 2SC4618TLN CPH6501-TL-E BC856BW-13-F US6T6TR BAX18/A52R BC556/112 IMZ2AT108 MMST8098T146 MCH6102-TL-E BC846B-13-F 2N3879 30A02MH-TL-E NTE13 NTE282 NTE323 NTE350 NTE81 JANTX2N2920L JANSR2N2907AUB CMLT3946EG TR SNSS40600CF8T1G CMLT3906EG TR GRP-DATA-JANS2N2907AUB GRP-DATA-JANS2N2222AUA MMDT3946FL3-7 2N4240 JANS2N3019 MSB30KH-13 2N2221AUB 2SD1815T-TL-E 2N6678 2N2907Ae4